General Purpose Transistors

NPN Silicon

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications.

Features

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CEO}	40	Vdc
Collector - Base Voltage	V _{CBO}	60	Vdc
Emitter - Base Voltage	V _{EBO}	6.0	Vdc
Collector Current - Continuous	I _C	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) @T _A = 25°C Derated above 25°C	P _D	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) @T _A = 25°C Derated above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	400	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 x 1.0 Inch Pad

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



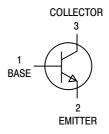
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GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT



SOT-416/SC-75 CASE 463 STYLE 1



MARKING DIAGRAM



AM = Device Code
M = Date Code*

• = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT3904TT1G	SOT-416 (Pb-Free)	3,000 Tape & Reel
SMMBT3904TT1G	SOT-416 (Pb-Free)	3,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTE	RISTICS			•		
Collector – Emitter (I _C = 1.0 mAdc,	Breakdown Voltage (Note 3) I _B = 0)	V _(BR) CEO	40	-	Vdc	
Collector – Base B (I _C = 10 μAdc, I	reakdown Voltage E = 0)	V _(BR) CBO	60	-	Vdc	
Emitter – Base Bre (I _E = 10 μAdc, I _c		V _{(BR)EBO}	6.0	-	Vdc	
Base Cutoff Curre (V _{CE} = 30 Vdc,		I _{BL}	-	50	nAdc	
Collector Cutoff C (V _{CE} = 30 Vdc,		I _{CEX}	-	50	nAdc	
ON CHARACTER	ISTICS (Note 3)	· · · · · · · · · · · · · · · · · · ·		*		
DC Current Gain	V _{CE} = 1.0 Vdc) V _{CE} = 1.0 Vdc)	h _{FE}	40 70 100 60 30	- 300 - -	-	
Collector – Emitter (I _C = 10 mAdc, (I _C = 50 mAdc,		V _{CE(sat)}	- -	0.2 0.3	Vdc	
Base – Emitter Sat (I _C = 10 mAdc, (I _C = 50 mAdc,	I _B = 1.0 mAdc)	V _{BE(sat)}	0.65 -	0.85 0.95	Vdc	
SMALL-SIGNAL	CHARACTERISTICS	· · · · · · · · · · · · · · · · · · ·				
Current – Gain – B (I _C = 10 mAdc,	landwidth Product V _{CE} = 20 Vdc, f = 100 MHz)	f⊤	300	-	MHz	
Output Capacitano (V _{CB} = 5.0 Vdc,	ce I _E = 0, f = 1.0 MHz)	C _{obo}	-	4.0	pF	
Input Capacitance (V _{EB} = 0.5 Vdc,	I _C = 0, f = 1.0 MHz)	C _{ibo}	-	8.0	pF	
Input Impedance (V _{CE} = 10 Vdc,	I _C = 1.0 mAdc, f = 1.0 kHz)	h _{ie}	1.0	10	kΩ	
Voltage Feedback (V _{CE} = 10 Vdc,	Ratio $I_C = 1.0 \text{ mAdc}, f = 1.0 \text{ kHz})$	h _{re}	0.5	8.0	X 10 ⁻⁴	
Small – Signal Cur (V _{CE} = 10 Vdc,	rent Gain I _C = 1.0 mAdc, f = 1.0 kHz)	h _{fe}	100	400	_	
Output Admittance (V _{CE} = 10 Vdc,	e I _C = 1.0 mAdc, f = 1.0 kHz)	h _{oe}	1.0	40	μmhos	
Noise Figure (V _{CE} = 5.0 Vdc,	$I_C = 100 \; \mu Adc, \; R_S = 1.0 \; k \; \Omega, \; f = 1.0 \; kHz)$	NF	-	5.0	dB	
SWITCHING CHA	RACTERISTICS					
Delay Time	(V _{CC} = 3.0 Vdc, V _{BE} = -0.5 Vdc) MMBT3904TT1G, SMMBT3904TT1G	t _d	_	35		
Rise Time	(I _C = 10 mAdc, I _{B1} = 1.0 mAdc) MMBT3904TT1G, SMMBT3904TT1G	t _r		35	ns	
Storage Time	$(V_{CC} = 3.0 \text{ Vdc}, I_C = 10 \text{ mAdc})$ MMBT3904TT1G, SMMBT3904TT1G	t _s		200		
Fall Time (I _{B1} = I _{B2} = 1.0 mAdc) MMBT3904TT1G, SMMBT3904TT1G		t _f	_	50		
	•					

^{3.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

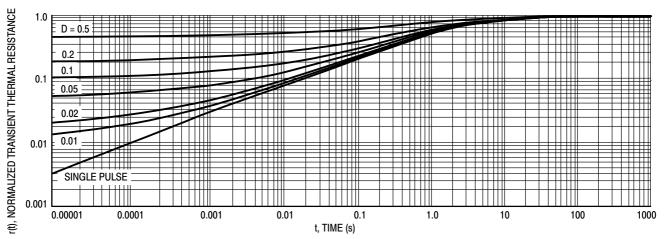
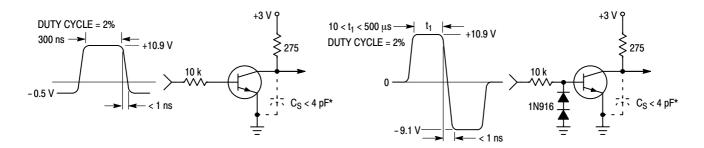


Figure 1. Normalized Thermal Response



* Total shunt capacitance of test jig and connectors

Figure 2. Delay and Rise Time Equivalent Test Circuit

Figure 3. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS

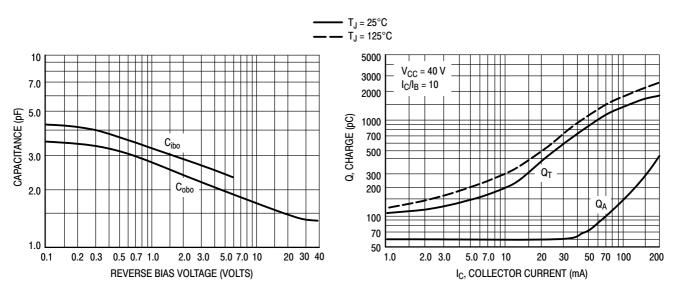
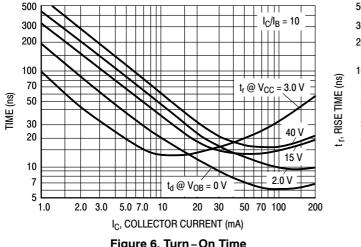


Figure 4. Capacitance

Figure 5. Charge Data



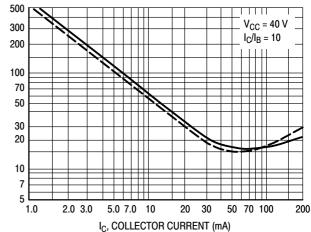
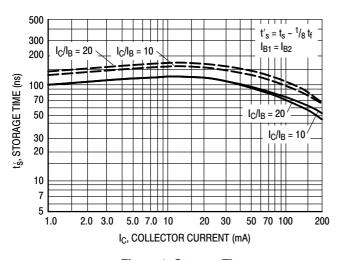


Figure 6. Turn-On Time

Figure 7. Rise Time



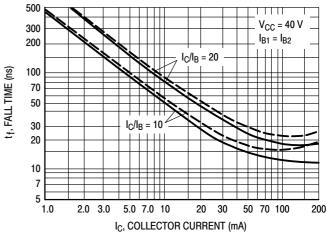
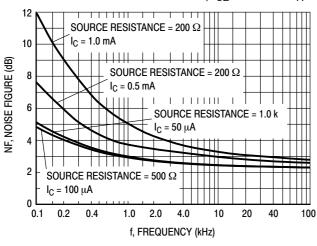


Figure 8. Storage Time

Figure 9. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS **NOISE FIGURE VARIATIONS**

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



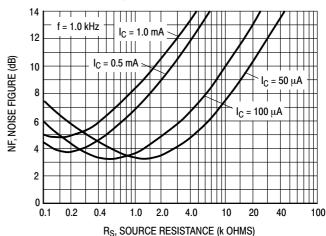
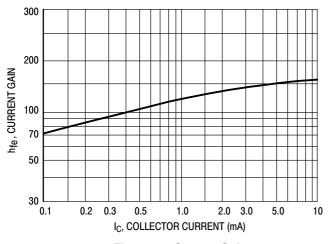


Figure 10. Noise Figure

Figure 11. Noise Figure

h PARAMETERS

 $(V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$



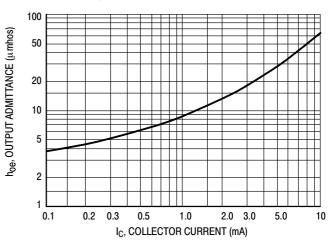
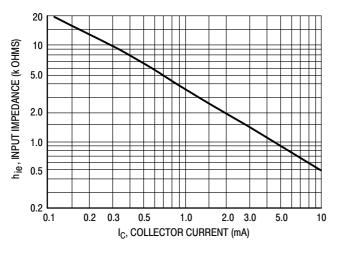


Figure 12. Current Gain

Figure 13. Output Admittance



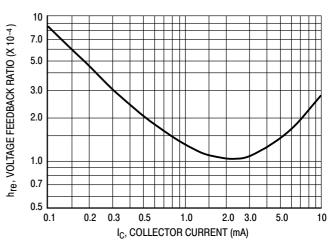


Figure 14. Input Impedance

Figure 15. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

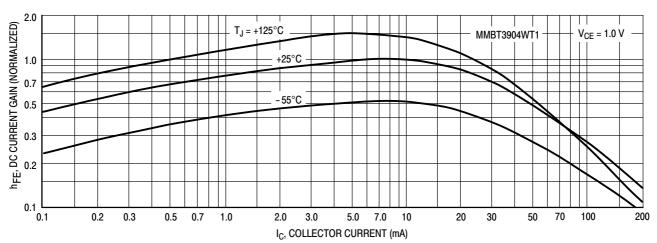


Figure 16. DC Current Gain

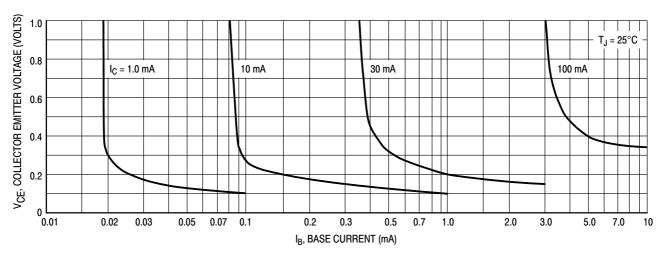


Figure 17. Collector Saturation Region

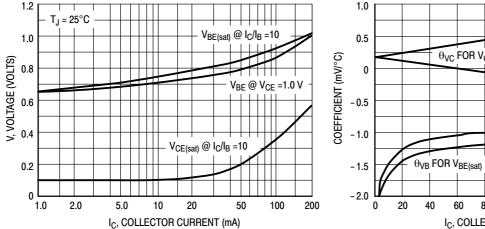


Figure 18. "ON" Voltages

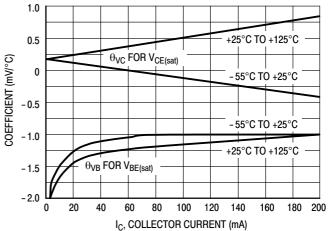
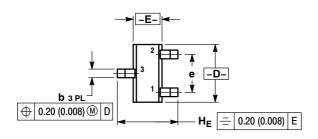
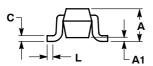


Figure 19. Temperature Coefficients

PACKAGE DIMENSIONS

SC-75/SOT-416 CASE 463-01 ISSUE F





NOTES

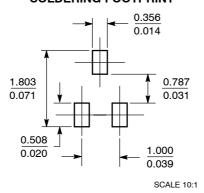
- DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS				;	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
Е	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC			(0.04 BSC)
Ĺ	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

mm

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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